

# iscN-Channel MOSFET Transistor

TK7A55D

#### • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(ON) = 1.25Ω (MAX)
- Enhancement mode:
  Vth = 2.4 to 4.4V (V<sub>DS</sub> = 10 V, I<sub>D</sub>=1.0mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

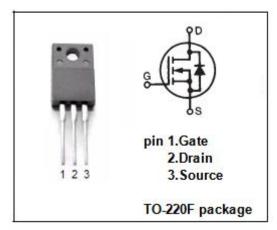
· Switching Voltage Regulators

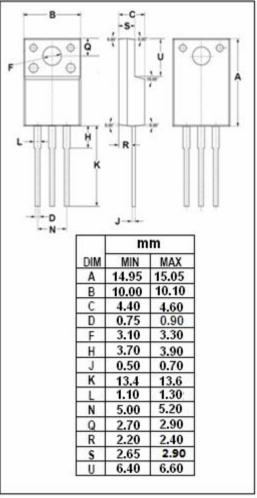
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	550	V
V <sub>GS</sub>	Gate-Source Voltage	±30	٧
lo	Drain Current-Continuous	7	Α
I <sub>DM</sub>	Drain Current-Single Pulsed	28	Α
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	35	W
Tj	Max. Operating Junction Temperature 150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.57	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	550			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2.4		4.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =3.5A			1.25	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =550V; V <sub>GS</sub> = 0V			10	μА
$V_{SDF}$	Diode forward voltage	I <sub>DR</sub> =7A, V <sub>GS</sub> = 0 V			1.7	٧



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